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REVISION HISTORY

Version	Date	Descriptions
Rev. 1.0	03/2023	Initial version

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

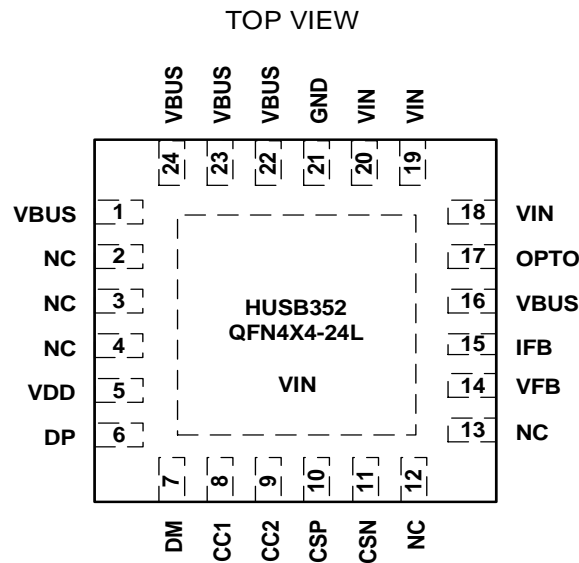


Figure 2. Pin Configuration (Top View)

Table 1. HUSB352-AAXXX-QN24R Pin Function Descriptions

Pin No.	Pin Name	Type1	Description
1、16、22、23、24	VBUS	AI	Output of the integrated power switch. Connect this pin to USB Type-C connector.
2、3、4、12、13	NC	-	No connection.
5	VDD	P	Internal 3.3V regulator output for system power.
6	DP	DIO	USB DP line.
7	DM	DIO	USB DM line.
8	CC1	AIO	USB Type-C CC1 line.
9	CC2	AIO	USB Type-C CC2 line.
10	CSP	AI	Positive input of the current sense amplifier.
11	CSN	AI	Negative input of the current sense amplifier.
14	VFB	AI	Feedback point of Constant Voltage (CV) loop, connect CV compensation network to this pin.
15	IFB	AI	Feedback point of Constant Current (CC) loop, connect CC compensation network to this pin.
17	OPTO	AI	OPTO driver.
18、19、20	VIN	P	Supply voltage input. Connect this pin to GND via a recommended 1μF ceramic capacitor.
21	GND	P	Power ground.
-	PAD	P	QFN package pad. VIN of the integrated power switch. It is connect this pin to VIN.

Legend:

A = Analog Pin

P = Power Pin

D = Digital Pin

I = Input Pin

O = Output Pin

RECOMMENDED OPERATING CONDITIONS

Table 2.

Parameter	Rating
VIN Input Voltage	3.15 V to 12.6 V
Operating Temperature Range (Junction) (T _J)	-40 °C to 125 °C
Ambient Temperature Range (T _A)	-40 °C to 105 °C

SPECIFICATIONS

V_{IN} = 5 V, T_A = 25 °C, unless otherwise noted.

Table 3.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
POWER SUPPLY						
Supply Voltage	V _{IN}	Rising edge	3.15		12.6	V
Supply Voltage UVLO Threshold	V _{IN_UVLO}			3.1		V
Supply Voltage UVLO Hysteresis	V _{IN_UVLO_HYS}			150		mV
Supply Current	I _{CC}	CC is attached with a R _d , normal operation		2.8		mA
Quiescent Current	I _Q	CC1 and CC2 pins are floating		500		μA
VDD						
Internal Regulator Output	V _{DD}			3.3		V
Type-C						
1.5 A Mode Pull-Up Current Source	I _{RP_1P5}		165.6	180	194.4	μA
3.0 A Mode Pull-Up Current Source	I _{RP_3P0}		303.6	330	356.4	μA
BMC COMMON PARAMETERS						
Bit Rate	f _{BitRate}		270	300	330	kbps
BMC Tx PARAMETERS						
Falling Time	t _{Fall}	10% and 90% amplitude points, unloaded condition	300			ns
Rising Time	t _{Rise}	10% and 90% amplitude points, unloaded condition	300			ns
Voltage Swing	V _{Swing}	CC pull down resistor > 800Ω	1.05	1.125	1.2	V
Transmitter Low Voltage	V _{Low}	CC pull down resistor > 800Ω	-75		75	mV
Transmitter Output Impedance	Z _{Driver}	Source output impedance at 750kHz with CC attached	35	55	75	Ω
BMC Rx PARAMETERS						
Rx Bandwidth Limiting Filter	t _{RXFilter}	Time constant of a single pole filter	100			ns
Receiver Input Impedance	Z _{BMC_RX}		1			MΩ
BC1.2 DCP MODE						
DP and DM Shorting Resistance	R _{DPM_SHORT}	V _{DP} = 0.6 V		30		Ω
DP Leakage Resistance	R _{DP_LKG}	V _{DP} = 0.6 V		800		kΩ
DM Leakage Resistance	R _{DM_LKG}	V _{DM} = 0.6 V		800		kΩ
DIVIDER3 MODE						
DP Output Voltage	V _{DP_APP}	V _{IN} = 5 V		2.7		V
DM Output Voltage	V _{DM_APP}	V _{IN} = 5 V		2.7		V

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
DP Output Impedance	R _{DP_PAD}	I _{DP} = -5 μ A		30		k Ω
DM Output Impedance	R _{DM_PAD}	I _{DM} = -5 μ A		30		k Ω
HVDCP MODE						
Output Voltage Selection Reference	V _{SEL_REF}			2.0		V
Data Detect Voltage	V _{DAT_REF}			0.325		V
DP High Glitch Filter Time	T _{GLITCH_BC_MODE}		1	1.25	1.5	s
DM Low Glitch Filter Time	T _{GLITCH_DM_LOW}		1	2		ms
Output Voltage Glitch Filter Time	T _{GLITCH_V_CHANGE}		20	40	60	ms
DM Pull-Down Resistance	R _{DM_DWM}			15		k Ω
QC MODE						
Pulse Glitch Filter Time	T _{GLITCH_CONT_CHANGE}	For QC3.0 in continues mode	100	150	200	μ s
FCP MODE						
DM FCP TX Valid Output High	V _{TX_VOH}		2.55		3.6	V
DM FCP TX Valid Output Low	V _{TX_VOL}				0.3	V
DM FCP RX Valid Input High	V _{RX_VIH}		1.4		3.6	V
DM FCP RX Valid Input Low	V _{RX_VIL}				1	V
DM Output Pull-Low Resistance	R _{DPL}			500		Ω
Unit Interval for FCP	UI			160		μ s
VOLTAGE CONTROL (VFB PIN)						
Voltage Sense Scaling Factor				10		
VIN Step LSB				20		mV
Default Voltage	V _{IN_DEF}	CC is unattached. Default setting.		5.12		V
VIN Regulation Accuracy		V _{IN} =3.15 V to 12.6 V		± 1.5		%
CURRENT CONTROL (CS+, IFB PINs)						
Current Sense Resistor				5		m Ω
OPTO PIN						
Minimum OPTO Current				30		μ A
Maximum Pull Down Current				3		mA
POWER SWITCH						
ON Resistance		VIN pin to VBUS pin		15		m Ω
OVER VOLTAGE PROTECTION						
OVP Protection Threshold	V _{IN_OV}	Reference to internal V _{IN} reference, no offset voltage applied. Default setting.	115	120	125	%
OVP De-bounce Time	t _{OVP_DEB}			10		μ s
UNDER VOLTAGE PROTECTION						
UVP Protection Threshold	V _{IN_UV}	Reference to internal V _{IN} reference	75	80	85	%
UVP De-bounce Time	t _{UVP_DEB}			1		ms
OVER CURRENT PROTECTION						
OCP Protection Threshold	I _{IN_OC}	Reference to internal I _{IN} reference. Default setting. Nominal output current=3 A		120		%
OCP De-bounce Time	t _{OC_DEB}			2.5		ms
FOCP Protection Threshold	I _{IN_FOCP}			6		A

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
THERMAL SHUT DOWN						
Thermal Shut Down Threshold	T _{TSD}			140		°C
Thermal Shut Down Hysteresis	T _{TSD_HYS}			20		°C

ABSOLUTE MAXIMUM RATINGS

Table 4.

Parameter	Rating
VIN, VBUS to GND	−0.3 V to 16 V
OPTO, CC1, CC2 to GND	−0.3 V to 16 V
VDD, DP, DM, CS+, VFB, IFB to GND	−0.3 V to 7 V
Operating Temperature Range (Junction)	−40°C to 125°C
Soldering Conditions	JEDEC J-STD-020
Soldering Reflow Peak Temperature	260°C
Electrostatic Discharge (ESD)	
Human Body Model	±2000 V
Charged Device Model	±2000 V

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

THERMAL RESISTANCE

Thermal performance is directly linked to printed circuit board (PCB) design and operating environment. Close attention to PCB thermal design is required.

θ_{JA} is the natural convection junction to ambient thermal resistance measured in a one cubic foot sealed enclosure.

θ_{JC} is the junction to case thermal resistance.

Table 5. Thermal Resistance

Package Type	θ_{JA}	θ_{JC}	Unit
QFN-24L, 4 mm x 4 mm	52	23	°C/W

ESD CAUTION



Electrostatic Discharge Sensitive Device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

THEORY OF OPERATION

VIN PIN

VIN pin is the power supply input, which is derived from the output of the AC-DC or DC-DC converter. Connect a 1 μ F decoupling MLCC between VIN pin and GND pin.

The VIN pin is also connected to an internal MOSFET and discharge resistor, which is used as a bleeder to help discharge the energy stored in the output capacitor. With this bleeder, VIN can be regulated to vSafe5V upon the detachment of a connected device, or to a lower desired output voltage level upon a request command received from the Sink, such as from 12 V to 5 V.

VDD PIN

An internal linear regulator is used to provide 3.3 V for internal circuits. Connect a 1 μ F MLCC to VDD pin for decoupling.

CONTROL LOOP COMPENSATION CIRCUIT (VFB, CS+, IFB, OPTO PINS)

In the [HUSB352](#), the constant voltage loop (CV loop) compensation and constant current loop (CC loop) compensation are implemented. VIN voltage is scaled by a resistor divider to be as the feedback voltage. It is compared with the internal voltage reference to generate an error signal. The CV loop can compensate this error signal. And then the compensated signal is employed to drive the primary side of the opto-coupler and control the AC-DC power loop.

SLEW RATE CONTROL

The [HUSB352](#) implements multiple fixed voltage slew rates, which are 250 mV/ms, 167 mV/ms, 100 mV/ms and 83 mV/ms. The default setting is 83 mV/ms.

IR COMPENSATION

IR compensation is only available when VIN is set to 5 V. If PPS is available in any power level, IR compensation will be disabled even if 5 V APDO is selected. There are 4 IR compensation options, 0 mV/A, 50 mV/A, 100 mV/A and 150 mV/A. The default IR compensation is 100 mV/A.

For example, if 100 mV/A IR compensation is selected, then for the 5 V/3 A condition (except 5 V APDO), the actual VIN voltage is:

$$5\text{ V} + 3\text{ A} \times 100\text{ mV/A} = 5.3\text{ V}$$

CURRENT SENSE RESISTOR

The recommended current sense resistor is 5 m Ω . The sensed current information is employed to perform OCP, FOCP and Constant Current Control.

CC1 AND CC2 PINS

CC1 and CC2 pins are used to detect Type-C connection, BMC communication.

TYPE-C CC FUNCTION

CC1 and CC2 are the Configuration Channel pins used for connection and attachment detection, plug orientation determination and system configuration management across USB Type-C cable.

The [HUSB352](#) monitors the status of CC1 and CC2 pins and decide which state the [HUSB352](#) should enter.

CC1 and CC2 are configured as Source only mode with 1.5 A and 3 A current advertising. The default R_p current on CC1 and CC2 is I_{CC_3P0} , which means 3 A current advertising.

The CC1 and CC2 can tolerance a voltage up to 16 V. This is helpful for the [HUSB352](#) to survive in the failure when the CC1 or CC2 is shorted to the VBUS pin.

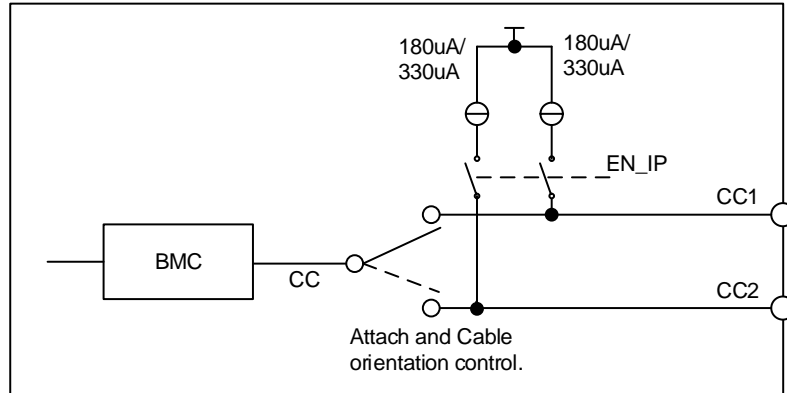


Figure 3. CCx Hardware Diagram

BMC DRIVER

Through the Type-C detection, one of the CC pins will be connected to the internal BMC block to achieve PD communication.

VBUS PIN

This pin is used to sense VBUS presence and discharge VBUS voltage on USB Type-C receptacle side.

VSAFE0V DETECTION

When the [HUSB352](#) is attached with a Sink, it detects whether the VBUS voltage is within vSafe0V. If yes, the [HUSB352](#) enters Attached.SRC state. If no, it will stay at AttachWait.SRC state.

VBUS DISCHARGE

The VBUS pin is also connected to an internal MOSFET and discharging circuitry, which is used as a bleeder to help dissipate the energy stored in the VBUS capacitor. With this bleeder, VBUS is discharged to vSafe0V upon the detachment of a connected device, or to a lower desired output voltage level upon a request command received from the Sink, such as from 12 V to 5 V.

OVER VOLTAGE PROTECTION

The [HUSB352](#) detects the VIN pin voltage to achieve over-voltage protection function. The threshold to trigger over-voltage protection is 120% of the VIN_REF. When the over-voltage condition occurs, the [HUSB352](#) turns off the internal load switch. When the over-voltage condition is removed, the [HUSB352](#) is reset to default mode and will automatic recover again.

UNDER VOLTAGE PROTECTION

The [HUSB352](#) detects the VIN pin voltage to achieve under-voltage protection function. The threshold to trigger under-voltage protection is 80% of the VIN_REF. When the under-voltage condition occurs, the [HUSB352](#) turns off the internal load switch. When the over-voltage condition is removed, the [HUSB352](#) is reset to default mode and will automatic recover again.

OVER CURRENT PROTECTION

When the current sensed by the sense resistor exceeds the 120% of IIN_REF, the over-current protection takes action and turns off the internal load switch. When the over-current condition is removed, the [HUSB352](#) is reset to default mode and will automatic recover again.

FAST OVER CURRENT PROTECTION

The [HUSB352](#) integrates FOCV protection function. When the VBUS is hard shorted to GND by fault, the output current increases sharply. When the output current reaches the FOCV threshold, the protections circuit takes action and turns off the internal load switch. When the short condition is removed, the [HUSB352](#) is reset to default mode and will automatic recover again.

THERMAL SHUT DOWN

When the junction temperature rises across T_{TSD} , thermal shut down takes action and turns off the internal load switch. When the junction temperature falls across $T_{TSD}-T_{TSD_HYS}$, the HUSB352 is reset to default mode and will automatic recover again.

CHARGING PROTOCOLS AUTO SELECTION (DP AND DM PINS)

The HUSB352 supports various fast charging protocols including BC1.2 DCP, Divider3, QC 2.0/3.0 Class A, AFC, FCP and SCP. According to the different status of DP and DM pins, the HUSB352 recognizes the attached sinks and apply the fast charging protocol automatically.

DPDM_APP MODE

The DPDM_APP mode is the mode that the HUSB352 supports the Divider3 charging protocol. In the DPDM_APP mode, the HUSB352 outputs 2.7 V DC voltage on both DP and DM pins. The 2.7 V can be pulled down by the attached Sink. If DP or DM pin is pulled down below V_{SEL_REF} , the HUSB352 exits the DPDM_APP mode and enters into DPDM_DCP mode.

DPDM_DCP MODE

The DPDM_DCP mode is the mode that the HUSB352 supports BC1.2 DCP protocol. The 2.7 V DC sources are removed and the DP and DM pins are shorted through R_{DPM_SHORT} resistor. It is possible for the attached Sink to start primary, secondary and HVDCP detection processes when the HUSB352 is in DPDM_DCP mode.

DPDM_HVDCP MODE

After successful detection of the DCP, the HUSB352 notify the Sink that the HUSB352 enters into HVDCP mode.

In the HVDCP mode, the HUSB352 monitors the DP and DM pin status and enters into different modes depending on the status of DP and DM pins.

TYPICAL APPLICATION CIRCUITS

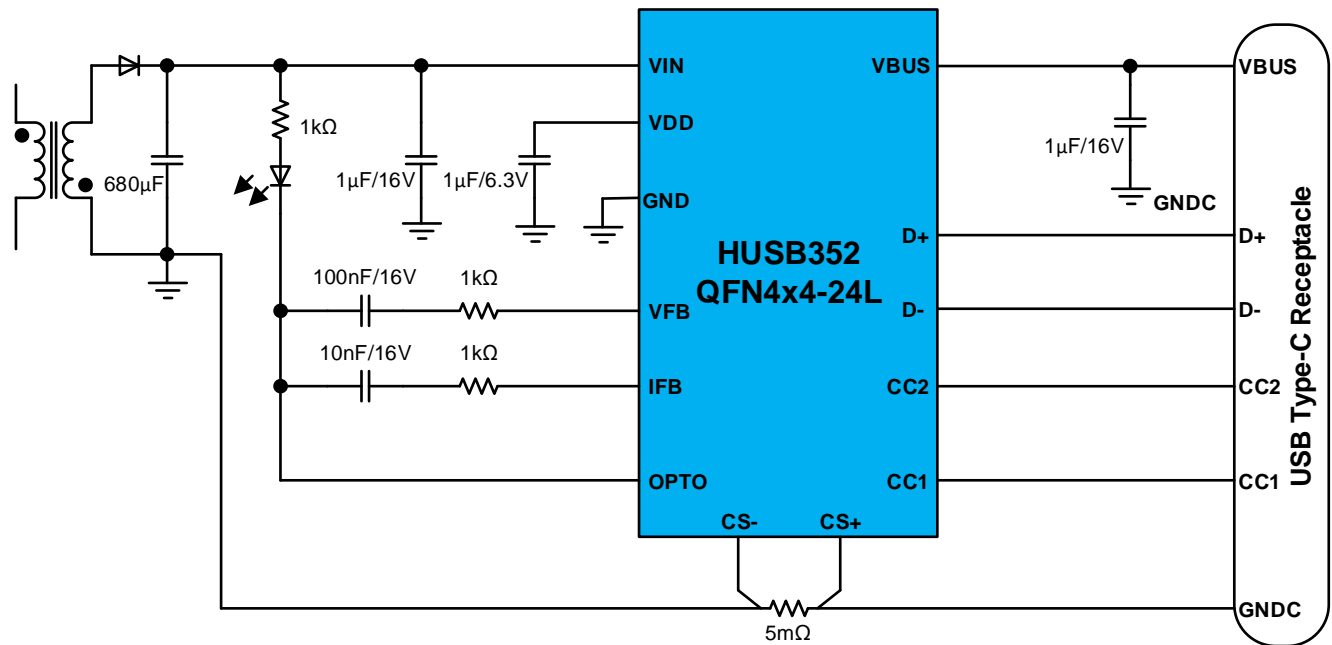
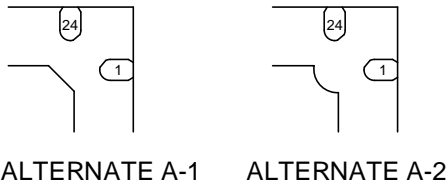
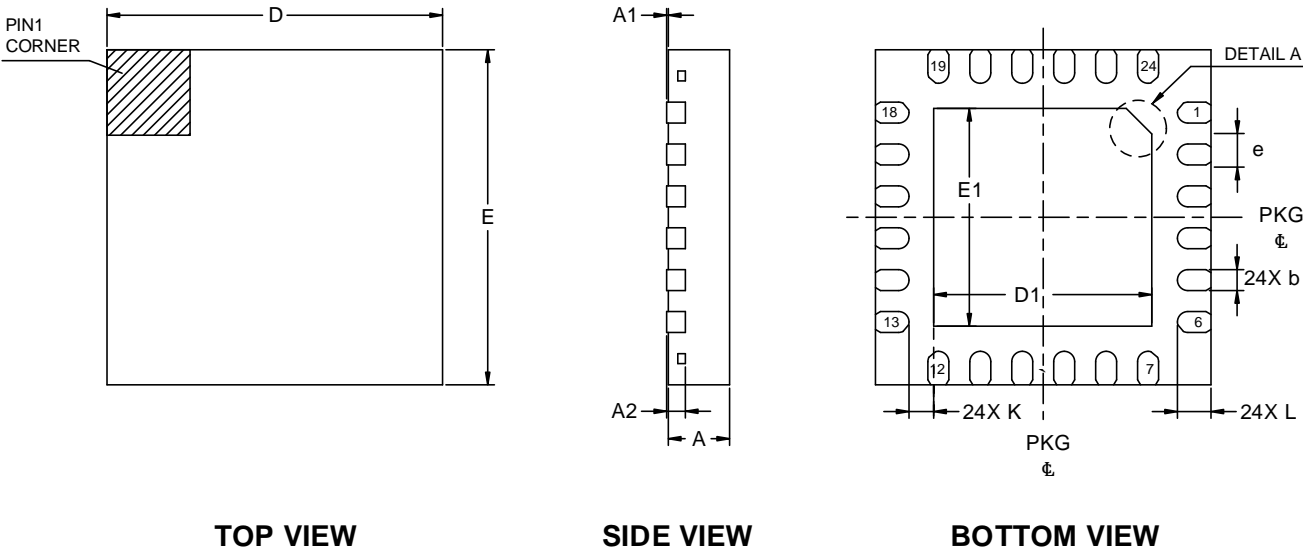


Figure 4. USB PD Source with HVDCP Protocol Supported Application Diagram

PACKAGE OUTLINE DIMENSIONS



DETAIL A: ALTERNATE PIN#1 ID. CONSTRUCTIONS

SYMBOLS	DIMENSION IN MILLIMETERS		
	MIN	NOM	MAX
A	0.70	0.75	0.80
A1	0.000	0.02	0.05
A2	0.203 REF		
b	0.20	0.25	0.30
D	4.00 BSC		
E	4.00 BSC		
D1	2.40	2.50	2.80
E1	2.40	2.50	2.80
e	0.50 BSC		
L	0.30	0.40	0.50
k	0.20 MIN		

Figure 5. QFN-24L Package, 4mm x 4mm

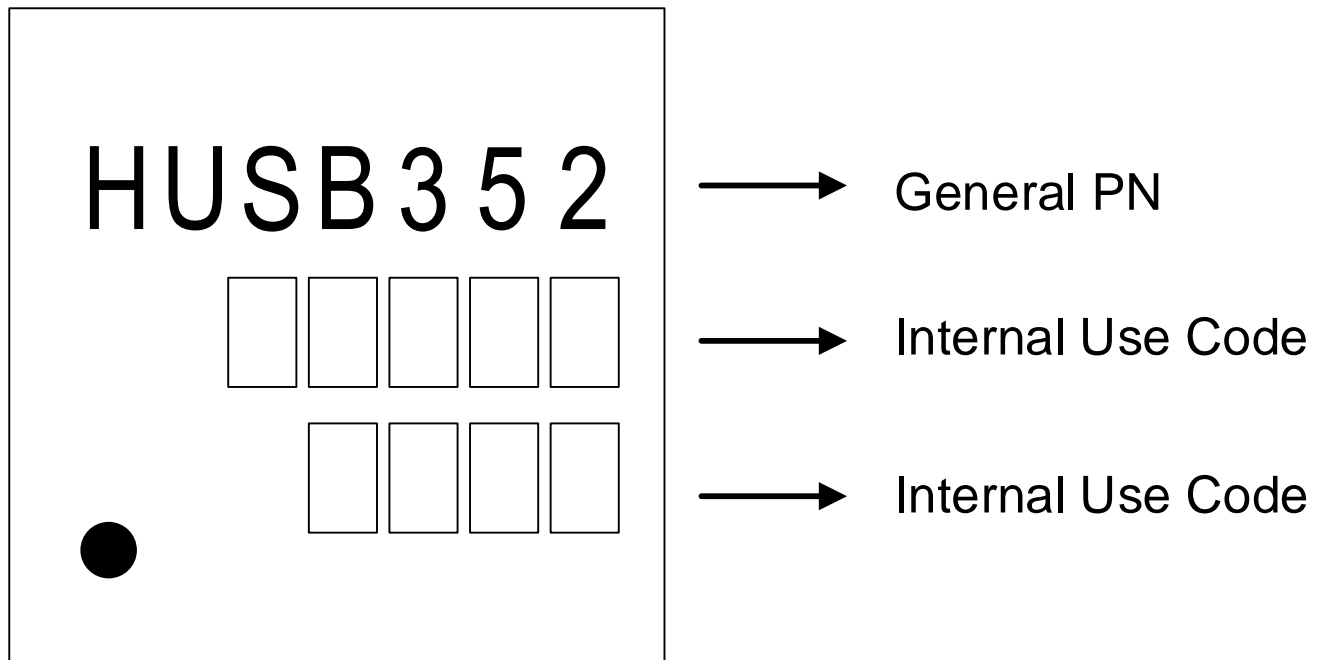
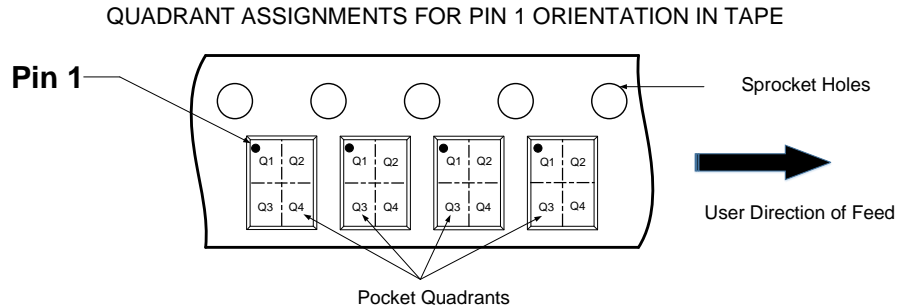
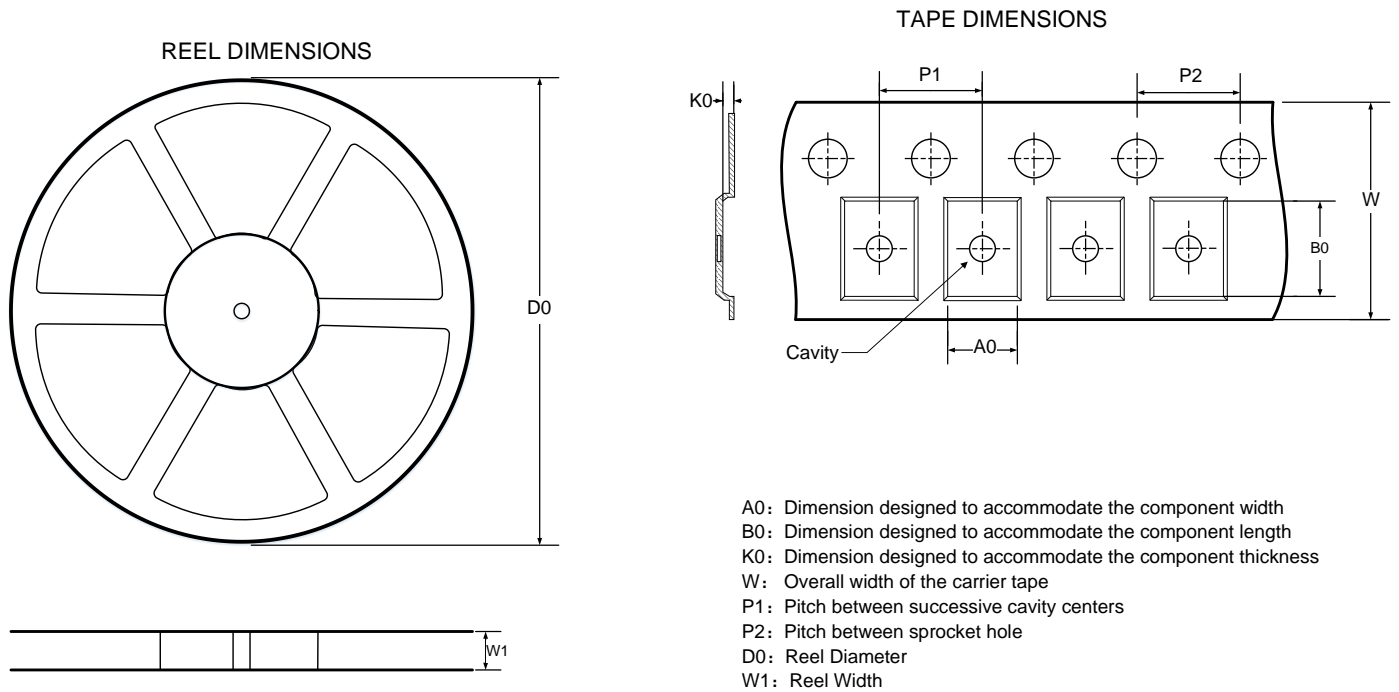
PACKAGE TOP MARKING

Figure 6. HUSB352 Package Top Marking

ORDERING GUIDE

Model	Power Configurations	T _J Temp (°C)	Package Type	Package Option	Package Qty
HUSB352-AA001-QN24R	5 V/3 A 9 V/2.22 A 12 V/1.67 A PPS1 3.3-5.9 V 3 A PPS2 3.3-11 V 2.2 A	-40 to 125	QFN-24L, 4 mm x 4 mm	Tape & Reel	5000
HUSB352-AAXXX-QN24R	Customizable, Contact Hynetek	-40 to 125	QFN-24L, 4 mm x 4 mm	Tape & Reel	5000

TAPE AND REEL INFORMATION



DIMENSIONS AND PIN1 ORIENTATION

Device	Package Type	D0 (mm)	W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant	Quantity
HUSB352-AA001-QN24R	QFN4X4-24L	330	13.40	4.30	4.30	1.10	8.00	4.00	12.00	Q1	5000.00
HUSB352-AAXXX-QN24R											

All dimensions are nominal

Figure 7. Tape and Reel Information

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